

## R-C Thermal Model Parameters

### DESCRIPTION

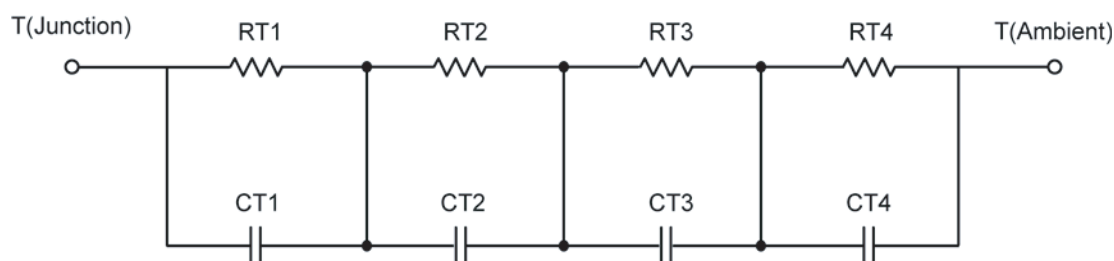
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

*Note:*

*For a detailed explanation of implementing these values in P-SPIICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPIICE Platform](#).*

### R-C THERMAL MODEL FOR TANK CONFIGURATION



| <b>R-C VALUES FOR TANK CONFIGURATION</b> |            |            |      |
|--|------------|------------|------|
| Thermal Resistance (°C/W)                |            |            |      |
| Junction to                              | Ambient    | Case       | Foot |
| RT1                                      | 4.3079     | 238.6633 m | N/A  |
| RT2                                      | 7.4677     | 291.1519 m | N/A  |
| RT3                                      | 13.8423    | 1.1148     | N/A  |
| RT4                                      | 58.8764    | 1.0727     | N/A  |
| Thermal Capacitance (Joules/°C)          |            |            |      |
| Junction to                              | Ambient    | Case       | Foot |
| CT1                                      | 5.2101 m   | 266.7345 m | N/A  |
| CT2                                      | 42.1039 m  | 5.0160     | N/A  |
| CT3                                      | 173.3669 m | 1.1623 m   | N/A  |
| CT4                                      | 1.0551     | 8.8689 m   | N/A  |

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**

**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance (°C/W)       |            |            |      |
|---------------------------------|------------|------------|------|
| Junction to                     | Ambient    | Case       | Foot |
| RF1                             | 6.8528     | 1.3023     | N/A  |
| RF2                             | 11.7756    | 686.0837 m | N/A  |
| RF3                             | 14.1535    | 452.3654 m | N/A  |
| RF4                             | 51.9506    | 262.6024 m | N/A  |
| Thermal Capacitance (Joules/°C) |            |            |      |
| Junction to                     | Ambient    | Case       | Foot |
| CF1                             | 5.3726 m   | 982.6144 u | N/A  |
| CF2                             | 40.8226 m  | 7.1323 m   | N/A  |
| CF3                             | 205.7289 m | 25.0532 m  | N/A  |
| CF4                             | 943.3135 m | 5.7964     | N/A  |

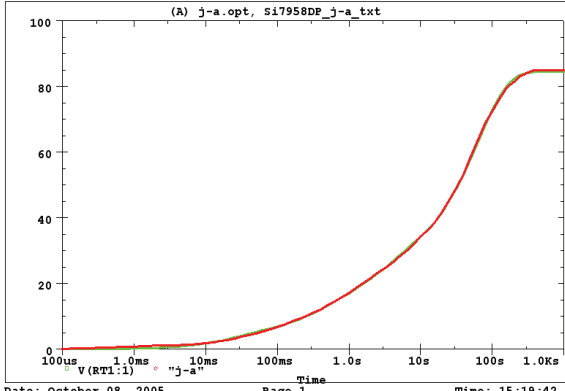
Note: NA indicates not applicable

Reference:

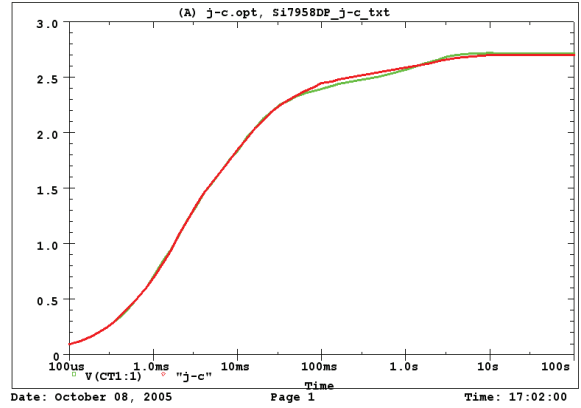
[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya, IEEE / SEMITHERM 2002



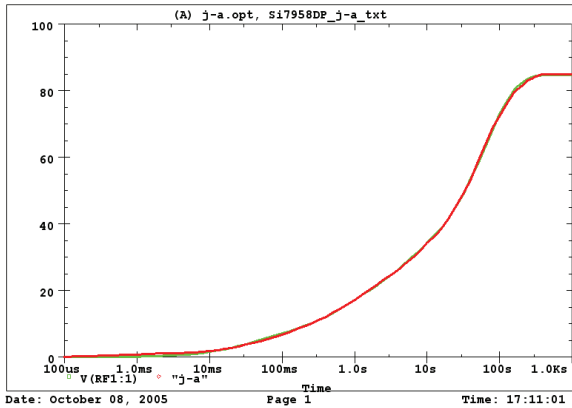
si7958DP Tank j-a Temperature: 27.0



si7958DP Tank j-c Temperature: 27.0



si7958DP Filter j-a Temperature: 27.0



si7958DP Filter j-c Temperature: 27.0

